74AUP2G241

Low-power dual buffer/line driver; 3-state

Rev. 10 — 27 July 2023

Product data sheet

1. General description

The 74AUP2G241 provides a dual non-inverting buffer/line driver with 3-state outputs. The 3-state outputs are controlled by the output enable inputs 10E and 20E. A HIGH level at pin 10E causes output 1Y to assume a high-impedance OFF-state. A LOW level at pin 20E causes output 2Y to assume a high-impedance OFF-state.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

This device has an input-disable feature, which allows floating input signals. The input 1A is disabled when the output enable input $1\overline{OE}$ is HIGH. The input 2A is disabled when the output enable input 2OE is LOW.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- · High noise immunity
- · Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- · Input-disable feature allows floating input conditions
- I_{OFF} circuitry provides partial Power-down mode operation
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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3. Ordering information

Table 1. Ordering information

Type number	Package								
	Temperature range	Name	Description	Version					
74AUP2G241DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1					
74AUP2G241GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1					
74AUP2G241GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	SOT1116					
74AUP2G241GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	SOT1203					

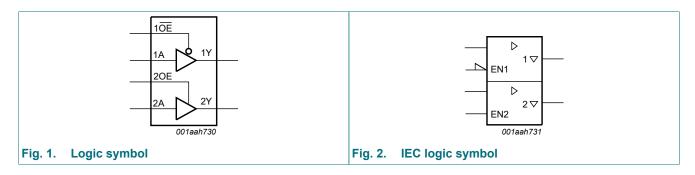
4. Marking

Table 2. Marking codes

Type number	Marking code[1]
74AUP2G241DC	p41
74AUP2G241GT	p41
74AUP2G241GN	p1
74AUP2G241GS	p1

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

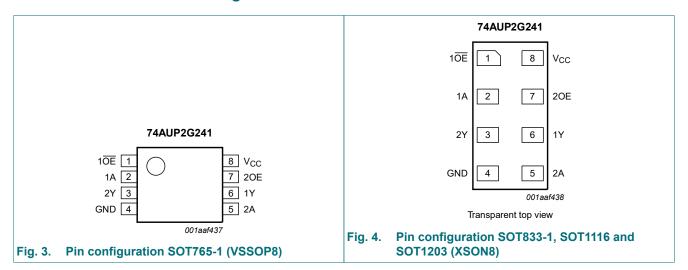
5. Functional diagram



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6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
1 OE	1	output enable input 1 OE (active LOW)
1A, 2A	2, 5	data input
1Y, 2Y	6, 3	data output
GND	4	ground (0 V)
20E	7	output enable input 2OE (active HIGH)
V _{CC}	8	supply voltage

7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care; \ Z = high-impedance \ OFF-state.$

-		Output	Input		Output
1 OE	1A	1Y	20E	2A	2Y
L	L	L	Н	L	L
L	Н	Н	Н	Н	Н
Н	Х	Z	L	Х	Z

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	$V_O = 0 \text{ V to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ [2]	-	250	mW

^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	0	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
T _{amb} = 25 °C								
V_{IH}	HIGH-level input	V _{CC} = 0.8 V	0.70V _{CC}	-	-	V		
	voltage	V _{CC} = 0.9 V to 1.95 V	0.65V _{CC}	.65V _{CC}	-	V		
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V		
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V		
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.30V _{CC}	V		
	voltage	V _{CC} = 0.9 V to 1.95 V	-	-	0.35V _{CC}	V		
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V		
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V		

^[2] For SOT765-1 (VSSOP8) package: Ptot derates linearly with 4.9 mW/K above 99 °C.

For SOT833-1 (XSON8) package: Ptot derates linearly with 3.1 mW/K above 68 °C.

For SOT1116 (XSON8) package: Ptot derates linearly with 4.2 mW/K above 90 °C.

For SOT1203 (XSON8) package: Ptot derates linearly with 3.6 mW/K above 81 °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	$I_O = -20 \mu A; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		$I_O = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.44	V
l _l	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	_	±0.1	μA
l _{OZ}	OFF-state output current	V _I = V _{IH} or V _{IL} ; V _O = 0 V to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.2	μΑ
ΔI _{OFF}	additional power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.2	μΑ
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.5	μΑ
ΔI _{CC}	additional supply current	data input; $V_I = V_{CC} - 0.6 \text{ V}$; $I_O = 0 \text{ A}$; [1] $V_{CC} = 3.3 \text{ V}$	-	-	40	μΑ
		$1\overline{OE}$ and 2OE input; V _I = V _{CC} - 0.6 V; [1] I _O = 0 A; V _{CC} = 3.3 V	-	-	110	μΑ
		all inputs; V_I = GND to 3.6 V; $1\overline{OE}$ = V_{CC} ; [2] 2OE = GND; V_{CC} = 0.8 V to 3.6 V	-	-	1	μΑ
Cı	input capacitance	V_{CC} = 0 V to 3.6 V; V_I = GND or V_{CC}	-	0.6	-	pF
Co	output capacitance	output enabled; V _O = GND; V _{CC} = 0 V	-	1.7	-	pF
		output disabled; V_{CC} = 0 V to 3.6 V; V_{O} = GND or V_{CC}	-	1.5	-	pF
T _{amb} = -4	40 °C to +85 °C					
V _{IH}	HIGH-level input	V _{CC} = 0.8 V	0.70V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.65V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.30V _{CC}	V
IL	voltage	V _{CC} = 0.9 V to 1.95 V	_	_	0.35V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	_	_	0.9	V

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}					
	voltage	I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V		V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V		0.7V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V		1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V		1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V		1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V		1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V	
		I _O = -4.0 mA; V _{CC} = 3.0 V		2.55	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}					
	voltage	I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V		-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V		-	-	0.3V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V		-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V		-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V		-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V		-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V		-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V		-	-	0.45	V
l _l	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V		-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V		-	-	±0.5	μA
I _{OZ}	OFF-state output current	V _I = V _{IH} or V _{IL} ; V _O = 0 V to 3.6 V; V _{CC} = 0 V to 3.6 V		-	-	±0.5	μΑ
Δl _{OFF}	additional power-off leakage current	V_{I} or $V_{O} = 0 \text{ V to } 3.6 \text{ V}$; $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$		-	-	±0.6	μA
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V		-	-	0.9	μА
ΔI _{CC}	additional supply current	data input; $V_I = V_{CC} - 0.6 \text{ V}$; $I_O = 0 \text{ A}$; $V_{CC} = 3.3 \text{ V}$	[1]	-	-	50	μA
		$1\overline{OE}$ and 2OE input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1]	-	-	120	μΑ
		all inputs; V_I = GND to 3.6 V; $1\overline{OE}$ = V_{CC} ; 2OE = GND; V_{CC} = 0.8 V to 3.6 V	[2]	-	-	1	μΑ
T _{amb} = -4	40 °C to +125 °C						
V _{IH}	HIGH-level input	V _{CC} = 0.8 V		0.75V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V		0.70V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V		1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V		2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V		-	-	0.25V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V		-	-	0.30V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V		-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V		-	-	0.9	V

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}					
	voltage	I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V	١	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V		0.6V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V		0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V		1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V		1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V		1.67	-	-	V
		I_{O} = -2.7 mA; V_{CC} = 3.0 V		2.40	-	-	V
		I_{O} = -4.0 mA; V_{CC} = 3.0 V		2.30	-	-	V
V _{OL} LOW-level output		$V_I = V_{IH}$ or V_{IL}					
	voltage	I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V		-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V		-	-	0.33V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V		-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V		-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V		-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V		-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V		-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V		-	-	0.50	V
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V		-	-	±0.75	μA
l _{OZ}	OFF-state output current	V _I = V _{IH} or V _{IL} ; V _O = 0 V to 3.6 V; V _{CC} = 0 V to 3.6 V		-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$		-	-	±0.75	μA
ΔI _{OFF}	additional power-off leakage current	V_{I} or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$ to 0.2 V		-	-	±0.75	μA
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V		-	-	1.4	μA
ΔI _{CC}	additional supply current	data input; $V_I = V_{CC}$ - 0.6 V; $I_O = 0$ A; $V_{CC} = 3.3$ V	[1]	-	-	75	μΑ
		$1\overline{OE}$ and 2OE input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1]	-	-	180	μΑ
		all inputs; V_I = GND to 3.6 V; $1\overline{OE}$ = V_{CC} ; 2OE = GND; V_{CC} = 0.8 V to 3.6 V	[2]	-	-	1	μΑ

^[1] [2] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND. To show I_{CC} remains very low when the input-disable feature is enabled.

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11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 8.

Symbol	Parameter	Conditions	T _{amb} = 25 °C			T _{an}	_{nb} = o +85 °C	T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 5 p	F			·						
t _{pd}	propagation	nA to nY; see Fig. 5 [2]								
	delay	V _{CC} = 0.8 V	-	20.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	5.5	10.5	2.5	11.7	2.5	12.9	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	3.9	6.1	2.0	7.3	2.0	8.1	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.2	4.8	1.7	6.1	1.7	6.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.6	2.6	3.6	1.4	4.3	1.4	4.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.4	3.1	1.2	3.9	1.2	4.4	ns
t _{en} enable time	enable time	1 OE to 1Y; see <u>Fig. 6</u> [3]								
		V _{CC} = 0.8 V	-	69.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.1	6.1	11.8	2.9	13.9	2.9	15.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	4.2	6.6	2.3	7.7	2.3	8.3	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	3.4	5.1	2.0	6.2	2.0	6.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	2.6	3.7	1.7	4.5	1.7	5.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	2.4	3.1	1.7	3.5	1.7	3.9	ns
		2OE to 2Y; see Fig. 7 [3]								
		V _{CC} = 0.8 V	-	71.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	6.2	12.4	2.6	13.6	2.6	13.6	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.2	6.9	2.2	7.4	2.2	7.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.3	5.3	1.7	5.9	1.7	6.2	ns
		V _{CC} = 2.3 V to 2.7 V	1.5	2.4	3.6	1.4	3.8	1.4	4.1	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	2.0	2.9	1.2	3.2	1.2	3.4	ns
t _{dis}	disable time	1 OE to 1Y; see <u>Fig. 6</u> [4]								
		V _{CC} = 0.8 V	-	14.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.7	4.3	6.5	2.7	7.3	2.7	8.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	3.2	4.4	2.1	5.1	2.1	5.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.0	4.3	2.0	5.0	2.0	5.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.4	2.2	2.9	1.4	3.3	1.4	4.1	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	2.5	3.2	1.7	3.4	1.7	3.9	ns
		20E to 2Y; see Fig. 7 [4]								
		V _{CC} = 0.8 V	-	10.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	4.2	6.2	2.9	6.4	2.9	6.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	3.2	4.4	2.2	4.6	2.2	4.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	3.1	4.4	1.7	4.6	1.7	4.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	2.4	3.2	1.4	3.4	1.4	3.6	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	2.8	3.6	1.2	3.7	1.2	3.8	ns

Symbol	Parameter	Conditions	T _{amb} = 25 °C			T _{ar} -40 °C t	_{nb} = o +85 °C	T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 10	pF									
t _{pd}	propagation	nA to nY; see Fig. 5 [2]								
	delay	V _{CC} = 0.8 V	-	24.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	6.4	12.3	3.0	13.8	3.0	15.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	4.5	7.3	1.9	8.5	1.9	9.4	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.8	5.5	1.7	6.8	1.7	7.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.2	4.2	1.6	5.3	1.6	5.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	3.0	3.8	1.6	4.6	1.6	5.2	ns
t _{en}	enable time	1 OE to 1Y; see <u>Fig. 6</u> [3]								
		V _{CC} = 0.8 V	-	73.7	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	6.9	13.5	3.4	15.8	3.4	17.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.8	7.7	2.2	8.6	2.2	9.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.9	5.8	1.9	6.8	1.9	7.4	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	3.2	4.3	1.7	5.3	1.7	5.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	3.0	3.9	1.7	4.3	1.7	4.8	ns
		2OE to 2Y; see Fig. 7 [3]								
		V _{CC} = 0.8 V	-	75.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	7.1	14.1	3.0	15.4	3.0	15.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.8	8.0	2.1	8.3	2.1	8.6	ns
		V _{CC} = 1.65 V to 1.95 V	1.8	3.9	5.9	1.7	6.5	1.7	6.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.5	2.9	4.2	1.4	4.5	1.4	4.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.6	3.6	1.3	3.8	1.3	4.0	ns
t _{dis}	disable time	1 OE to 1Y; see <u>Fig. 6</u> [4]								
		V _{CC} = 0.8 V	-	32.7	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.4	5.4	7.9	3.4	8.8	3.4	9.9	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.1	5.5	2.2	6.2	2.2	7.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	4.2	5.6	1.9	6.3	1.9	7.1	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	3.0	3.8	1.7	4.5	1.7	5.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	3.8	4.8	1.7	5.0	1.7	5.6	ns
		2OE to 2Y; see Fig. 7 [4]								
		V _{CC} = 0.8 V	-	12.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.5	5.3	7.6	3.3	7.9	3.3	7.9	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.1	5.6	2.1	5.7	2.1	5.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.4	4.2	5.7	1.7	5.8	1.7	6.0	ns
		V _{CC} = 2.3 V to 2.7 V	1.9	3.2	4.1	1.4	4.3	1.4	4.5	ns
		V _{CC} = 3.0 V to 3.6 V	2.4	4.1	5.0	1.3	5.2	1.3	5.3	ns

Symbol	Parameter	Conditions	T _{amb} = 25 °C			T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 15	pF									
t _{pd} propagation		nA to nY; see Fig. 5 [2]								
	delay	V _{CC} = 0.8 V	-	27.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	7.2	14.1	3.3	15.8	3.3	17.5	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.1	8.1	2.5	9.8	2.5	10.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	4.3	6.3	2.0	7.9	2.0	8.8	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.7	4.9	1.8	6.0	1.8	6.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.5	4.4	1.8	5.4	1.8	6.1	ns
t _{en}	enable time	1 OE to 1Y; see <u>Fig. 6</u> [3]								
		V _{CC} = 0.8 V	-	77.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.0	7.7	15.2	3.7	17.6	3.7	19.6	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.3	8.4	2.5	9.8	2.5	10.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.4	6.5	2.1	7.7	2.1	8.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.6	5.0	2.0	6.1	2.0	6.8	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.5	4.5	1.9	4.9	1.9	5.5	ns
		20E to 2Y; see Fig. 7 [3]								
		V _{CC} = 0.8 V	-	79.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	7.8	15.8	3.3	17.1	3.3	17.1	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.4	8.8	2.9	9.4	2.9	9.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	4.3	6.7	2.0	7.3	2.0	7.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	3.4	4.8	1.7	5.2	1.7	5.6	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	3.1	4.3	1.5	4.5	1.5	4.7	ns
t _{dis}	disable time	1 OE to 1Y; see <u>Fig. 6</u> [4]								
		V _{CC} = 0.8 V	-	60.8	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	6.5	9.2	3.7	10.3	3.7	11.6	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.0	6.5	2.5	7.4	2.5	8.4	ns
		V _{CC} = 1.65 V to 1.95 V	3.0	5.3	6.6	2.1	7.4	2.1	8.9	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.8	4.9	2.0	5.1	2.0	6.4	ns
		V _{CC} = 3.0 V to 3.6 V	2.9	5.0	6.2	1.9	6.6	1.9	7.4	ns
		20E to 2Y; see Fig. 7 [4]								
		V _{CC} = 0.8 V	-	14.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	6.4	8.5	3.7	9.3	3.7	9.4	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.0	6.6	2.5	6.9	2.5	7.0	ns
		V _{CC} = 1.65 V to 1.95 V	3.1	5.4	6.6	2.0	7.4	2.0	7.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.4	4.0	5.0	1.7	5.1	1.7	5.5	ns
		V _{CC} = 3.0 V to 3.6 V	3.2	5.3	6.2	1.5	6.7	1.5	6.9	ns

Symbol	Parameter	Conditions	T _{amb} = 25 °C			T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 30	pF									
t _{pd}	propagation	nA to nY; see Fig. 5 [2]								
d	delay	V _{CC} = 0.8 V	-	37.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.8	9.5	19.0	4.4	21.6	4.4	24.0	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	6.7	10.8	3.0	13.0	3.0	14.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.9	5.6	8.4	2.6	10.3	2.6	11.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	4.8	6.3	2.5	7.8	2.5	8.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.7	4.6	5.8	2.5	7.0	2.5	8.3	ns
t _{en}	enable time	1 OE to 1Y; see <u>Fig. 6</u> [3]								
		V _{CC} = 0.8 V	-	88.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	5.2	9.9	19.8	4.8	22.8	4.8	25.3	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	6.8	10.8	3.1	12.6	3.1	14.1	ns
		V _{CC} = 1.65 V to 1.95 V	3.0	5.6	8.5	2.8	10.2	2.8	11.3	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	4.8	6.5	2.6	7.8	2.6	8.8	ns
		V _{CC} = 3.0 V to 3.6 V	2.7	4.6	6.0	2.6	6.9	2.6	7.7	ns
		20E to 2Y; see Fig. 7 [3]								
		V _{CC} = 0.8 V	-	90.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.7	10.0	20.4	4.3	22.0	4.3	22.0	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	6.9	11.3	3.7	12.0	3.7	12.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	5.6	8.6	3.2	9.5	3.2	10.1	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	4.5	6.3	2.9	6.8	2.9	7.3	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	4.2	5.8	2.7	6.4	2.7	6.7	ns
t _{dis}	disable time	1 OE to 1Y; see <u>Fig. 6</u> [4]								
		V _{CC} = 0.8 V	_	49.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	6.0	9.9	13.3	4.8	14.8	4.8	16.5	ns
		V _{CC} = 1.4 V to 1.6 V	4.4	7.7	9.6	3.1	10.7	3.1	12.1	ns
		V _{CC} = 1.65 V to 1.95 V	5.1	8.7	11.1	2.8	12.4	2.8	13.8	ns
		V _{CC} = 2.3 V to 2.7 V	3.6	6.2	7.4	2.6	8.6	2.6	9.6	ns
		V _{CC} = 3.0 V to 3.6 V	5.2	8.7	10.5	2.6	10.8	2.6	13.1	ns
		20E to 2Y; see Fig. 7 [4]								
		V _{CC} = 0.8 V	_	51.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	6.0	9.8	13.6	4.7	14.3	4.7	14.4	ns
		V _{CC} = 1.4 V to 1.6 V	4.5	7.7	10.5	3.0	10.7	3.0	11.0	ns
		V _{CC} = 1.65 V to 1.95 V	5.2	8.8	11.4	2.6	11.5	2.6	11.6	ns
		V _{CC} = 2.3 V to 2.7 V	3.9	6.4	7.4	2.3	9.0	2.3	10.2	ns
		V _{CC} = 3.0 V to 3.6 V	5.5	9.0	10.7	2.2	10.8	2.2	12.0	ns

Low-power dual buffer/line driver; 3-state

Symbol	Parameter	Conditions	T _{amb} = 25 °C		T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 5 p	F, 10 pF, 15 p	F and 30 pF								
C _{PD}	power	$f = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}[5]$								
	dissipation capacitance	V _{CC} = 0.8 V	-	2.8	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.8	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.7	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.2	-	-	-	-	-	pF

- All typical values are measured at nominal V_{CC}.
- t_{pd} is the same as t_{PLH} and t_{PHL} . [2]
- [3] t_{en}^{r} is the same as t_{PZH} and t_{PZL} .
- [4]
- t_{dis} is the same as t_{PHZ} and t_{PLZ} . C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

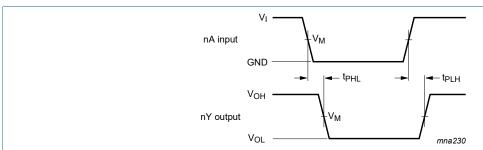
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

11.1. Waveforms and test circuit



Measurement points are given in <u>Table 9</u>.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 5. The data input (nA) to output (nY) propagation delays

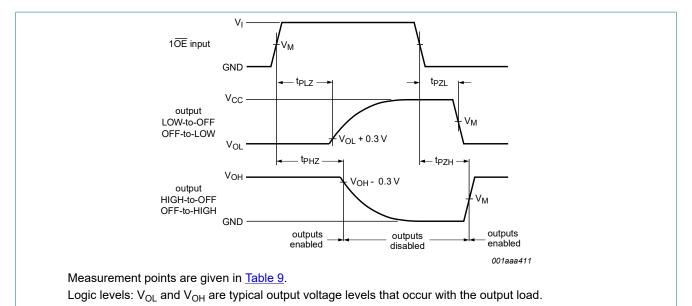


Fig. 6. 3-state enable and disable times

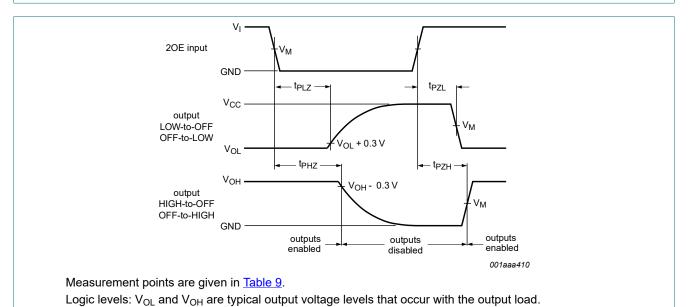
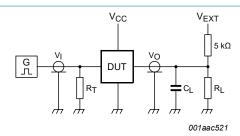


Fig. 7. 3-state enable and disable times

Table 9. Measurement points

Supply voltage	Input	nput			Output			
V _{CC}	V _M	VI	t _r = t _f	V _M	V _X	V _Y		
0.8 V to 1.6 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.1 V	V _{OH} - 0.1 V		
1.65 V to 2.7 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.15 V	V _{OH} - 0.15 V		
3.0 V to 3.6 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.3 V	V _{OH} - 0.3 V		

Low-power dual buffer/line driver; 3-state



Test data is given in Table 10.

Definitions for test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig. 8. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Load	V _{EXT}			
V _{CC}	C _L R _L [1]		t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

[1] For measuring enable and disable times R_L = 5 k Ω . For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

Low-power dual buffer/line driver; 3-state

12. Package outline

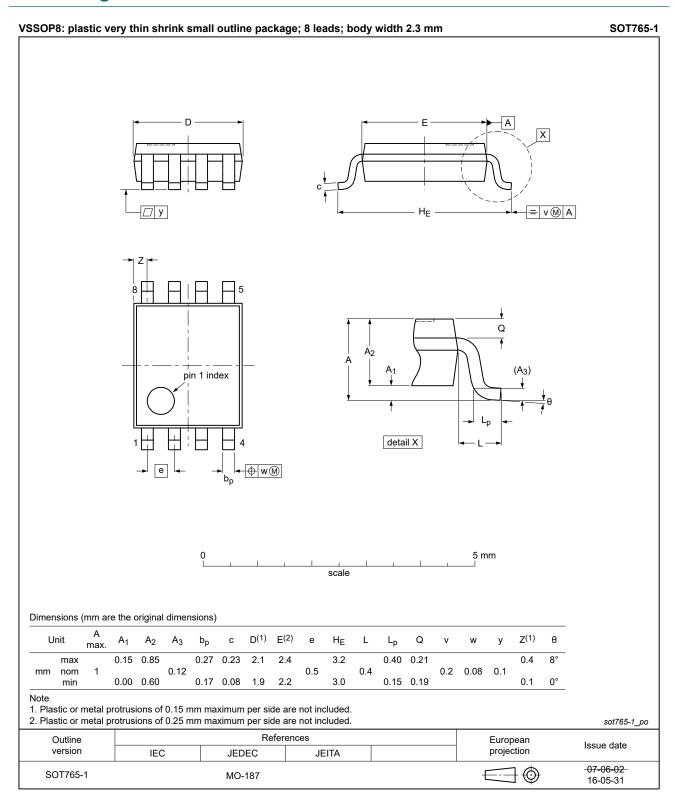


Fig. 9. Package outline SOT765-1 (VSSOP8)

Low-power dual buffer/line driver; 3-state

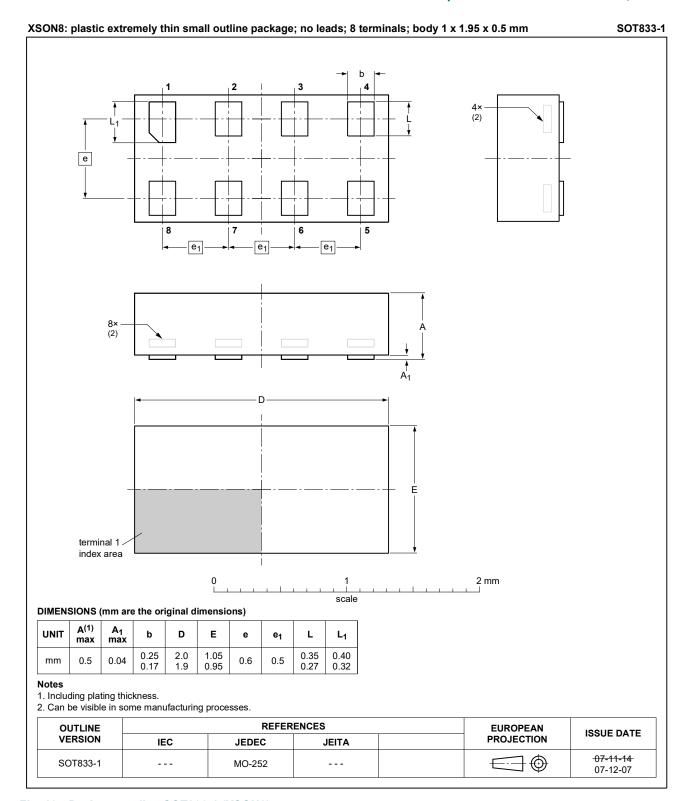


Fig. 10. Package outline SOT833-1 (XSON8)

Product data sheet

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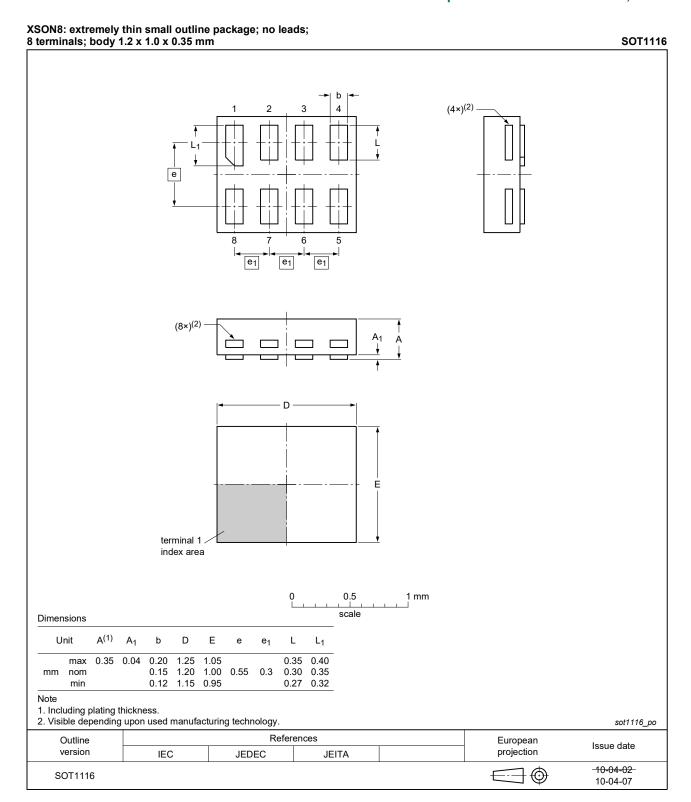


Fig. 11. Package outline SOT1116 (XSON8)

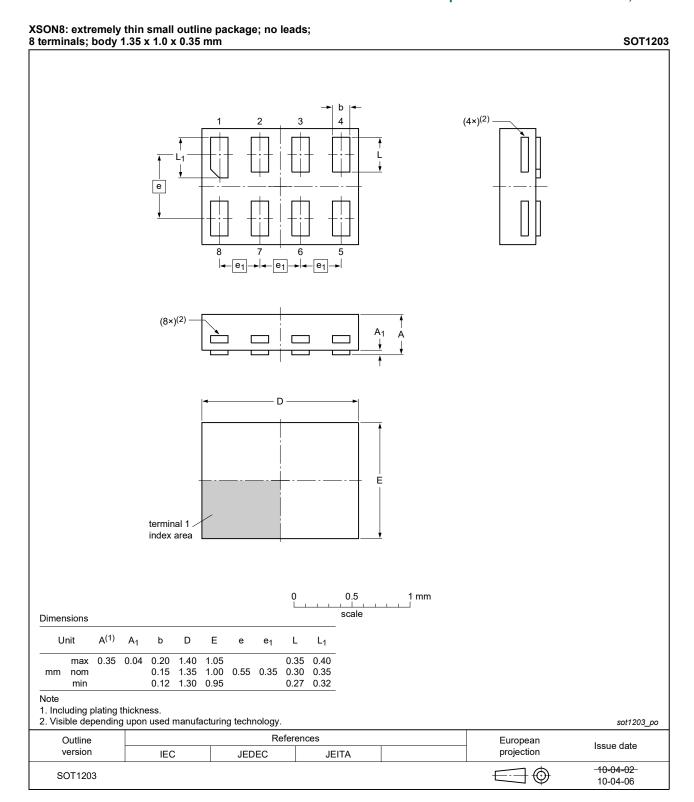


Fig. 12. Package outline SOT1203 (XSON8)

Low-power dual buffer/line driver; 3-state

13. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AUP2G241 v.10	20230727	Product data sheet	-	74AUP2G241 v.9			
Modifications:	Section 2: E	SD specification updated a	ccording to the lat	est JEDEC standard.			
74AUP2G241 v.9	20201201	Product data sheet	-	74AUP2G241 v.8			
Modifications:	 Type number 	 <u>Section 8</u>: Derating values for P_{tot} total power dissipation have been updated. Type numbers 74AUP2G241GF (SOT1089/XSON8) and 74AUP2G241GM (SOT902-2 XQFN8) removed. 					
74AUP2G241 v.8	20190321	Product data sheet	-	74AUP2G241 v.7			
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guideline of Nexperia. Legal texts have been adapted to the new company name where appropriate. Type number 74AUP2G241GD (XSON8/SOT996-2) removed. Package outline drawing SOT765-1 (VSSOP8) updated. Package outline drawing SOT902-2 (XQFN8) updated. 						
74AUP2G241 v.7	20130211	Product data sheet	-	74AUP2G241 v.6			
Modifications:	For type nur	nber 74AUP2G241GD XSC	N8U has change	d to XSON8.			
74AUP2G241 v.6	20120606	Product data sheet	-	74AUP2G241 v.5			
74AUP2G241 v.5	20111205	Product data sheet	-	74AUP2G241 v.4			
74AUP2G241 v.4	20100913	Product data sheet	-	74AUP2G241 v.3			
74AUP2G241 v.3	20090112	Product data sheet	-	74AUP2G241 v.2			
74AUP2G241 v.2	20080219	Product data sheet	-	74AUP2G241 v.1			
74AUP2G241 v.1	20061012	Product data sheet	-	-			

Low-power dual buffer/line driver; 3-state

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Low-power dual buffer/line driver; 3-state

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